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Mixed ionic-electronic conduction in NiFe$_2$O$_4$ – Ce$_{0.8}$Gd$_{0.2}$O$_{2-\delta}$ nanocomposite thin films for oxygen separation

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Abstract

NiFe$_2$O$_4$ - Ce$_{0.8}$Gd$_{0.2}$O$_{2-\delta}$ (NFO/CGO) nanocomposite thin films were prepared by simultaneously r.f. magnetron sputtering of both, NFO and CGO, ceramic targets. The aim is the growth of CO$_2$ stable composite layers that combine the electronic and ionic conduction of the separate NFO and the CGO phases for oxygen separation applications. The effect of the deposition temperature on the films microstructure was studied in order to obtain high quality composite thin films. The ratio of both phases was changed by applying different power to each ceramic target. The amount of each deposited phase as well as the different oxidation states of the nanocomposite constituents was analyzed by means of XPS. The transport properties were studied by total conductivity measurements as a function of temperature and $p$O$_2$. These analyses enabled to (1) select the best deposition temperature (400 °C), (2) correlate the $p$-type electronic behavior of the NFO phase with the hole hopping between Ni$^{3+}$ - Ni$^{2+}$ and (3) follow the conductivity behaviour of the grown composite layer (prevailing ionic or electronic character) attained by varying the amount of each phase. The nanocomposite sputtered layer exhibited high ambipolar conduction and surface exchange activity. A 150 nm-thick nano-grained composite thin film was deposited on a 20 μm-thick BSCF asymmetric membrane, obtaining up to 3.8 ml·min$^{-1}$·cm$^{-2}$ O$_2$ at 1000 °C under full CO$_2$ atmosphere.

Keywords: ceria; nanocomposite; Ionic conductor; sputtering; oxygen membrane
1. Introduction

The use of O₂ rich gas streams in several industrial processes is receiving a lot of attention, mainly due to the gain in sustainability and process efficiency. One of the most considered applications is oxyfuel technology, consisting of burning of a fuel with pure O₂, thus allowing more efficient combustion processes, minimizing NOₓ formation, and the direct CO₂ sequestration. [1] Nowadays, O₂ is mostly produced by highly energy-demanding and costly cryogenic air separation units and pressure-swing absorption. [2]. Oxygen transport membranes (OTMs) are a promising alternative technology that can be integrated in the industrial processes for on-site O₂ production for medium and small-scale applications instead traditional methods [3] [4].

OTMs consist of mixed ionic and electronic conductivity (MIEC) materials that allow the diffusion of O²⁻ (driven by an oxygen partial pressure gradient across the membrane) and electronic carriers in the opposite direction for charge compensation, obtaining a net O₂ separation with infinite selectivity. Permeation of O₂ when bulk diffusion is limiting is described by Wagner’s equation\(^1\), which determines that OTMs performance is affected by:
(i) the ambipolar conductivity of the constituent material (\(\sigma_{amb}\)), (ii) the membrane thickness (L), and (iii) the membrane operation conditions (\(pO₂\) gradient, temperature and atmosphere). Perovskite-type (ABO₃) membranes -and in particular Ba₀.₅Sr₀.₅Co₀.₈Fe₀.₂O₃₋₅ (BSCF) - exhibit the highest \(J(O₂)\) due to their high MIEC, although they are not stable in the harsh conditions that can be encountered in reactors and combustors (as CO₂, H₂O, SO₂ presence in the gas streams). A trade-off between good ionic and electronic conductivity and stability may be achieved by combining the best characteristics of different materials in a composite. These composites consist of (1) an electron conducting material, which allows the percolation of electrons, and (2) an ionic conductor that transports the O²⁻ through the membrane. The ceramic-ceramic (cercer) dual-phase compounds\(^5\) have been proposed as an economically attractive solution regarding composite OTMs. Several crystalline structures have been combined, demonstrating stability of both phases against reaction and

\[ \frac{RT}{16FL} \int_{pO₂}^{pO₂'} \sigma_{amb}(pO₂) dlnpO₂ \],
\(J(O₂)\) is the O₂ permeation flux in mol·m⁻²·s⁻¹, \(R\) is the gas constant, \(F\) is the Faraday constant, \(L\) is the membrane thickness, \(\sigma_{amb}\) is the ambipolar conductivity (\(\sigma_{amb} = \frac{\sigma_e \sigma_i}{\sigma_e + \sigma_i}\), where \(\sigma_i\) is the ionic and \(\sigma_e\) the electronic conductivities, respectively), and \(pO₂\) and \(pO₂'\) are the O₂ partial pressures at the high pressure side and low pressure side, respectively.
the compatibility of their thermal expansion coefficients (TEC) in order to produce mechanically resistant membranes, e.g. fluorites, perovskites, spinels and rock salts.\[^6\] While materials with perovskite and spinel structure are used as electronic conducting phase,\[^7\] fluorite materials constitute the oxygen conductor phase with high chemical stability.\[^8\]. In this way, different doped ceria fluorites and several spinel composite membranes have shown promising CO\(_2\) stable permeation properties.\[^9\]

In particular, NiFe\(_2\)O\(_4\) (NFO) and Ce\(_{0.9}\)Gd\(_{0.1}\)O\(_2-\delta\) (CGO10) were reported to be stable upon heating and cooling cycling between room temperature and 1000 °C in air and in an atmosphere with 50 vol % CO\(_2\) and 50 vol % N\(_2\).\[^10\] The thermal expansion coefficient (TECs) difference of both structures (10.3 × 10\(^{-6}\) K\(^{-1}\) of NFO and 11.9 × 10\(^{-6}\) K\(^{-1}\) of CGO10)\[^8\a, 11\] is within acceptable limits to the materials compatibility (15–25%).\[^12\] At 1000 °C, \(J(O_2)\) of 0.31 and 0.27 ml·min\(^{-1}\)·cm\(^{-2}\) were obtained on a 0.5 mm thick membrane for the sweep gases He and CO\(_2\), respectively.\[^10\] For industrial applications, a minimum of 3.5 ml·min\(^{-1}\)·cm\(^{-2}\) oxygen rate is required.\[^13\] Following Wagner equation predictions, the \(J(O_2)\) can be increased by decreasing membrane thickness \((L)\) as long as O\(_2\) transport is controlled by bulk diffusion, occurring above the critical length \((L_c)\), characteristic of each material.\[^14\] Hence, different methods to decrease the thickness of a dense membrane layer have been proposed e.g. screen printing,\[^15\] tape casting\[^16\], spray pyrolysis\[^17\] or r.f. magnetron sputtering\[^18\], for thinner layers.

Sputtering is a versatile method to produce thin films over a large area with a high uniformity. By optimizing the film, the properties of the layer can be tuned in terms of electrical transport or mechanical properties by adjusting the deposition parameters. For example, mechanical properties can be modified by controlling thin film thickness\[^19\] or fixing preferential orientation by selecting the substrate temperature\[^20\]. In addition, several targets can be co-sputtered at the same time giving the possibility of synthesize materials with a post-treatment,\[^21\] or forming composites\[^22\].

This work is focused on the study of thin films of composites made of NFO spinel and Ce\(_{0.8}\)Gd\(_{0.2}\)O\(_2-\delta\) (CGO) fluorite as electronic and ionic conducting phases, respectively, motivated by the high stability against CO\(_2\) showed by both NFO and CGO structures.\[^8\a, 8\b, 10\] The deposition of the cercer thin films was done by co-sputtering simultaneously NFO and CGO targets.\[^18\] Different deposition temperatures, atmospheres and r.f. power were
used for the thin film optimization, which was based on a thorough analysis of the thin films microstructure and their transport properties at high temperature. The transport properties were studied by DC conductivity and electrical conductivity relaxation, and correlated to the thin film characteristics, measured by XRD, FESEM, XPS, and AFM. Finally, composite permeation properties were tested by using an optimized thin film composite on a 20 µm BSCF asymmetric membrane, combining the high permeation flux of the BSCF and the stability properties of the NFO/CGO composite.

2. Experimental Section

Ce$_{0.8}$Gd$_{0.2}$O$_{2-\delta}$ (CGO) powder was purchased from Treibacher Industrie AG, while NiFe$_2$O$_4$ (NFO) powder was prepared by Pechini method.$^{[9d]}$ One inch ceramic targets were prepared by uniaxially pressing into pellets at (59.2 MPa) for 3 minutes and subsequently sintering in air at 1400 °C for 5 h. X-ray diffraction (XRD) of the sintered targets confirmed the complete formation of the corresponding fluorite and spinel structures, respectively.$^{[11, 23]}$ The thin films were deposited with a Pfeiffer Classic 250 deposition system equipped with two radiofrequency (13.56 MHz) sources. One inch NiFe$_2$O$_4$ and Ce$_{0.8}$Gd$_{0.2}$O$_{2-\delta}$ ceramic targets were used for sputtering of single films of each material and co-sputtering the cercer nanocomposite on a rotating substrate holder, with r.f. powers ranging from 8 to 25 W. The base pressure of the chamber before the deposition was 2 × 10$^{-6}$ mbar or lower. The working pressure was 2.9 × 10$^{-2}$ mbar with mixed argon-oxygen gas ratio 10/2. The distance target-substrate was kept to 5 cm and the substrate temperature was changed from room temperature (RT) up to 600 °C. Different thicknesses were deposited and controlled by deposition duration. All samples were deposited on Si (100) and amorphous quartz substrates in order to perform different characterizations.

The crystal structure of the films was checked by XRD measurements carried out by a PANalytical Cubix fast diffractometer, using CuK$_{\alpha1,2}$ radiation and an X’Celerator detector in Bragg-Brentano geometry.

The surface morphology of the films and the fracture cross sections were observed by ZEISS Ultra55 field emission scanning electron microscope (FESEM). The thickness of the films was determined from the fracture cross section FESEM images, preferably with
samples deposited on Si. The topography and roughness of the thin layers was measured by a Bruker Multimode 8 contact atomic force microscope (AFM).

The planar electrical conductivity of the films was measured by standard four-point DC technique, on films deposited on quartz substrates, by using silver wires and paste for contacting. Measurements were recorded as the temperature decreases from 800 to 400 ºC at 1 ºC/min at a constant atmosphere, in different oxygen partial pressures ($p_{O_2}$).[8a]

The electrical conductivity relaxation technique (ECR) was carried out in a tubular oven in which the gas volume was minimized in order to achieve an almost instantaneous $p_{O_2}$ change. Experiments were performed by measuring the impedance at a fixed frequency of 100 Hz with a Phase Sensitive Multimeter 1735 with an IAI interface from Newtons 4th Ltd.[8b, 24] The oxygen exchange kinetics was investigated by alternatively swapping oxygen partial pressure from 1 to 0.21 atm at some given temperatures. In this case, as we are measuring thin films, the relaxation is rate limited by the surface reaction, $k$, and values can be extracted from fittings to the ECR curves to equation (1):

$$g(t) = \frac{\sigma(t) - \sigma_0}{\sigma_{\infty} - \sigma_0} = 1 - Ae^{-\frac{t}{\tau}}$$

(1)

with $\tau = \frac{l}{k}$, where $l$ is the thickness of the film.[8b, 25]

Oxygen permeation studies were carried out in a lab-scale quartz reactor. The asymmetric membranes where the thin films were deposited were supplied by Forschungszentrum Jülich. The membranes consisted of all-Ba$_{0.5}$Sr$_{0.5}$Co$_{0.8}$Fe$_{0.2}$O$_{3-\delta}$ asymmetric membrane comprising a 20 µm-thick dense layer supported on a 750 µm-thick BSCF porous substrate. Synthetic air (21%, vol. O$_2$ in the feed stream) was fed into the oxygen-rich chamber, while argon and CO$_2$ mixtures were used as sweep gases on the permeate side in a 4-end mode configuration. Both streams were fed at atmospheric pressure. All streams were individually mass flow controlled. The temperature was measured by a thermocouple attached close to the membrane. A PID controller maintained temperature variations within 2 ºC of the set point. Membrane gas leak-free conditions were achieved using gold rings. The permeate was analyzed at steady state by online gas chromatography using a micro-GC Varian CP-4900 equipped with Molsieve5A, Pora-Plot-Q glass capillary, and CP-Sil modules. Membrane gas leak-free conditions were ensured by continuously monitoring the
nitrogen concentration in the product gas stream. An acceptable sealing was achieved when the ratio between the oxygen flow leak and the oxygen flux was lower than 3%. The data reported here were achieved at steady state after 1 h in the reaction stream. Each test was repeated three times to minimize the analysis error. The experimental analytical error was below 0.5%.

Surface analysis performed by X-ray photoelectron spectroscopy (XPS) was carried out on PHI Quantera equipment with a base pressure in the analysis chamber of 10⁻⁹ mbar. The X-ray source was monochromatic Al Kα radiation (1486.6 eV) and the overall energy resolution is estimated at 0.65 eV by the full width at half-maximum (FWHM) of the Au4f7/2 photoelectron line (84 eV). The charging effect was minimized by using a dual beam (electrons and Ar ions) as neutralizer while the spectra were calibrated using the C1s line (BE = 284.8 eV) of the adsorbed hydrocarbon on the sample surface (C-C and/or (CH)n bondings). As this spectrum was recorded at the start and at the end of each experiment the energy calibration during experiments was reliable. For in depth analysis, the incidence angle of the ion beam was 45° and the sputter rate was ~2.5 nm/min

3. Results and discussion

Prior to NFO-CGO thin film deposition by co-sputtering, the deposition of each material was studied independently. NFO thin film deposition was optimized in a previous work¹⁸ and the obtained films show a structure that matches that of the reported NFO bulk cubic spinel.¹¹ NFO films show predominant p-type electronic conductivity in contrast to the n-type electronic behaviour reported for the bulk. This difference is assigned to the higher amount of Ni³⁺ in the films due to the creation of cation vacancies in the ferrite lattice, that produce the hole hopping between Ni³⁺ - Ni²⁺.²⁶ The Ni³⁺/Ni²⁺ ratio was measured by XPS, which corroborates that the films have double ratio (0.42) than the bulk.¹⁸

Similar conditions as in the case of NFO thin films were selected for the CGO films deposition. As deposited, the film grown at RT is amorphous, deduced from the absence of any diffraction peaks. When the deposition temperature is increased, the crystallization of the CGO films is produced and the obtained films show different preferential orientations depending on the deposition temperature.
NFO/CGO composite films were grown by co-sputtering process of NFO and CGO simultaneously. The amount of the different phases was firstly estimated from the deposition rate of each material (NFO/CGO 25/75 vol.%) and afterwards calculated from XPS analysis. Figure 1a shows the XRD patterns of the as deposited at RT, 400 and 600 ºC NFO/CGO composite films. The composite grown at RT is predominantly amorphous, as expected from the identical behaviour of NFO and CGO single films and ascribed to the very low energy applied for the deposition, which was not sufficient for the crystal formation. At higher temperatures, 400 and 600 ºC, conditions at which both materials have shown enough energy for crystallization, obtained XRD patterns only show intensive peaks corresponding to the CGO while NFO peaks show very low intensity. Furthermore, as in the case of the single CGO films, CGO phase shows preferential (111) and (200) orientation for depositions at 400 and 600 ºC, respectively. These temperature dependent texture orientations were previously reported for other CGO and CeO$_2$ thin films, although no unified explanation exists from theoretical and experimental points of view.[27] After thin film annealing at 800 ºC for 2 h shown in Figure 1b, the pattern peaks are narrower, as corresponds to the grain growth with temperature, the CGO preferential orientation remains and the NFO phase is better defined, although its intensity is much lower than that of CGO due to the lower amount of this phase, as expected from the deposition rate of each material.
The surface morphology of the aforementioned NFO/CGO composite films is depicted in Figure 2. FESEM analysis reveals dense, homogenous and crack-free surfaces at the different deposition temperatures (Figure 2a, b and c) and after the annealing process at 800 °C in air for 2 h (d, e and f, respectively). Although the grain size growth caused by the thermal treatment is evident (also from XRD analysis), the small grain size of both components does not allow a clear distinction between NFO and CGO grains. The corresponding cross-section images of each annealed sample are also showed in the insets of Figure 2. Furthermore, there is a thickness difference that corresponds to distinct deposition time. An electron backscatter diffraction (EBSD) analysis was performed to

Figure 1: XRD patterns of three different NFO/CGO composite films deposited at RT, 400 and 800 °C (a) as grown and (b) after annealing in air for 2 hour at 800 °C. NFO and CGO reference patterns are also showed for comparison. r.f. 25/25 W
identify both crystalline phases, but no signal could be detected to the limit of the technique and due to the small diffraction domains inside the particles.

![Figure 2](image_url)

Figure 2: FESEM images of different composite films deposited at RT (a), 400 ºC (b) and 800 ºC (d) and after annealing in air for 2 h at 800 ºC (d), (e) and (f), respectively. r.f. 25/25 W. Note that the image of the as-deposited sample at 400 ºC was taken after 3 s Pt sputter deposition.

The microstructure after the annealing at 800 ºC of the thin film deposited at 400 ºC was studied more in detail by means the AFM and SEM analysis (Figure 3). The thin films are smooth, with surface roughness of Ra ≈ 7 nm. AFM and SEM images reveal the presence of two different phases, one with bigger grains (up to 100 nm) than the other one. Although it was not possible to determine by EDX which phase corresponds to which microstructure (due to the very small grain size) the images present a good distribution of both of them. In fact, the apparent connection between grains of the same phase will be translated into continuous electronic and ionic pathways for ambipolar oxygen transport, respectively, as it is later checked. Considering the grain morphology, polyhedral shapes are typically obtained for NFO with respect to CGO that tends to form globular grains.
The composition ratios NFO/CGO, and oxidation states of the composite constituent elements of thin films sputtered under different conditions were analyzed by XPS. Ni2p3/2 XPS spectra is depicted in Figure 7a, b and c. The Ni$^{3+}$/Ni$^{2+}$ ratio was calculated from the deconvolution of the spectra, obtaining values of 0.49, 0.39 and 0.54 for the samples.
deposited at RT, 400 and 600 °C, respectively. The estimated errors related to these values are in the range of ±5%. These values are closer to the 0.5 ratio observed in the NFO thin films with regard to the 0.16 ratio observed in NFO bulk material, which has shown to have an impact on the electronic conductivity behaviour.[18]

Figure 4: Ni2p3/2 XPS deconvoluted spectra in the “as received” (surface) stage for NFO-CGO films deposited at RT (a), 400 (b) and 600 °C (c)

Table 1 summarizes the XPS results for the films sputtered at different temperatures. The spectra were recorded in the as-received state to avoid any sputter induced changes in the oxidation states. Indeed, the sensitivity of ceria to Ar ion etching is well known even under very gentle setup conditions. Iron surface chemistry (Supplementary information Figure S1b, e, h) shows the features of a mixture of 3+ and 2+ oxidation states evidenced by both the 2p3/2 binding energies and the shape of the spectra (the presence of satellites). The sample deposited at 600 °C shows the highest percentage of Fe3+ on the as-received surface while the samples deposited at RT and 400 °C display a lower content of this oxidation state. O1s deconvoluted spectra (Figure S1a, d and g) show three features assigned to oxygen bonded in the lattice (O2−), OH groups and H2O adsorbed on the top of the surface layer (see Table 1). Ce3d and Ce4d photoelectron spectra (Figure S1c and f) are typical spectral fingerprint for 4+ oxidation state. It is worth to mention that the Ce4+ valence state is not affected by the used deposition method. Previous reports highlighted the presence of Ce3+ on thin films, as a result of the different parameters used in similar sputtering deposition method.[28] This conclusion can be drawn from both Ce3d and Ce4d characteristic spectra as compared to the reference spectrum presented in the Supplementary information, Figure S2. Finally, Gd3d5/2 lines (showed in Supplementary information, Figure S1 i) are characteristic of Gd3+, assignment strengthen by recording
Gd4d spectrum (Figure S1 f) as well as our own reference sample (see Supplementary information, Figure S3).

Table 1: Binding energies (BEs) of the most prominent XPS transitions (C1s, O1s, Ni2p3/2, Fe2p and Gd3d5/2)

<table>
<thead>
<tr>
<th>Sample</th>
<th>Binding energy (eV)</th>
<th>C1s</th>
<th>O1s</th>
<th>Ni2p3/2</th>
<th>Fe2p</th>
<th>Gd3d5/2</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>284.8</td>
<td>529.4 (O2-)</td>
<td>854.4 (Ni2+/NiO)</td>
<td>710.6</td>
<td>1187.0</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>531.6 (OH)</td>
<td>855.8 (Ni3+/Ni2O3)</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>532.7 (H2O)</td>
<td>856.3 (Ni2+/Ni(OH)2)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>400</td>
<td></td>
<td>284.8</td>
<td>529.5 (O2-)</td>
<td>854.3 (Ni2+/NiO)</td>
<td>710.6</td>
<td>1187.1</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>531.4(OH)</td>
<td>855.8 (Ni3+/Ni2O3)</td>
<td></td>
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<td></td>
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<td></td>
<td>532.9(H2O)</td>
<td>856.4 (Ni2+/Ni(OH)2)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>600</td>
<td></td>
<td>284.8</td>
<td>530.1(O2-)</td>
<td>854.5 (Ni2+/NiO)</td>
<td>710.9</td>
<td>1186.8</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>531.5(OH)</td>
<td>855.8 (Ni3+/Ni2O3)</td>
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<tr>
<td></td>
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<td></td>
<td>533.0(H2O)</td>
<td>856.6 (Ni2+/Ni(OH)2)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>CGO target</td>
<td>284.8</td>
<td>528.7(O2-)</td>
<td>531.4(OH)</td>
<td>-</td>
<td>-</td>
<td>1186.7</td>
</tr>
<tr>
<td>CGO thin film</td>
<td>284.8</td>
<td>528.5(O2-)</td>
<td>531.6(OH)</td>
<td>-</td>
<td>-</td>
<td>1186.6</td>
</tr>
<tr>
<td>NFO target</td>
<td>284.8</td>
<td>529.9(O2-)</td>
<td>531.5(OH)</td>
<td>854.7 (Ni2+/NiO)</td>
<td>710.7</td>
<td>-</td>
</tr>
<tr>
<td></td>
<td></td>
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<td>532.9 (H2O)</td>
<td>855.9 (Ni3+/Ni2O3)</td>
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<tr>
<td>NFO film</td>
<td>284.8</td>
<td>530.0(O2-)</td>
<td>531.5(OH)</td>
<td>854.6 (Ni2+/NiO)</td>
<td>710.8</td>
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<td>532.8 (H2O)</td>
<td>855.9 (Ni3+/Ni2O3)</td>
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The NFO/CGO ratio of both phases was calculated from XPS analysis (XPS depth profiles shown in Supporting Figure S4). In depth profile of the XPS spectra (Figure 8a-c) show that there is a carbon layer (likely from adsorbed hydrocarbons) confined on a few surface monolayers, especially on the samples deposited at 400 and 600 °C (~35 atom %). The phases buried under this deposit were detected after removal of this contaminant layer (1
min Ar ion etching). The profiles of the atom relative concentrations (atom%) are very similar for the samples deposited at RT and 600 °C, but differ from that corresponding to the sample deposited at 400 °C. While samples deposited at RT and 600 °C exhibit a homogeneous in-depth composition, the sample deposited at 400 °C shows an inhomogeneous in-depth phase distribution in the first layers. Therefore, the NFO/CGO (wt.%) ratios were calculated from the experimentally obtained concentrations after 12 min Ar ion etching (~ 35 nm), since the transport properties are related mainly to the bulk phase of our films (> 30 nm) rather than the outermost surface layer (< 2 nm). Thus, the obtained NFO/CGO (wt.%) values were 0.27, 0.17 and 0.24 for the samples deposited at RT, 400 and 600 °C, respectively.

![Figure 5](image_url)

**Figure 5:** The related in-depth relative concentrations determined from the corresponding XPS spectra (a) at RT; (b) at 400°C; and (c) at 600°C.

The impact of the microstructural characterization and surface of the thin films on the electrochemical transport properties of the sputtered layers was studied. The thermal behaviour of total conductivity of the NFO/CGO composites (Figure 4) is compared with grown NFO and CGO thin films and the bulk composite material. The conductivity of the composite films follows a similar Arrhenius behaviour than NFO, i.e. similar activation energy. The grown CGO films exhibits higher activation energy. The total conductivity of the thin films is lower than that reached by the NFO/CGO 60/40 bulk sample, while it is in between conductivity values of the NFO and the CGO thin films, closer to the latter due to the higher amount of this phase in the composite (~1/6). The nanocomposite thin films deposited at 400 and 600 °C show slightly smaller conductivity than that of the film deposited at RT, attributed to differences in the film microstructure (Figure 2).
\( pO_2 \) dependence of the conductivity at 700 °C of the different thin films and bulk reference material is shown in Figure 6. The behaviour of the thin films substantially differs from the bulk material. Namely, the bulk material (NFO/CGO 52/48 wt.) shows a slope close to -1/4, characteristic of a predominant \( n \)-type electronic conductor, while the film (NFO/CGO 1/6) show positive slopes of around 0.1-0.2. This slope for the composite film arises from an averaged (or additive) behaviour of both constituents, NFO and CGO films. Specifically, CGO film shows a nearly zero slope as expected from a pure ionic conductor while NFO film shows a \( \frac{1}{4} \) slope, as corresponds to a predominant \( p \)-type electronic conductor. This is in contrast to the bulk material, which exhibits a -1/4 slope typical of \( n \)-type electronic conductors.\(^{[18]}\) The particular \( n \)-type electronic conductivity of the NFO thin film is ascribed to the electron hopping between Fe\(^{3+} \) - Fe\(^{2+} \), while the NFO \( p \)-type conductivity is ascribed to the hole hopping between Ni\(^{3+} \) - Ni\(^{2+} \).\(^{[26, 30]}\)
In order to study the change of ambipolar conductivity of the deposited films with the NFO/CGO ratio, the sputtering conditions were varied. The content of CGO was decreased by reducing the applied power to the CGO target during the deposition and leaving constant the NFO applied power (25 W). The composite film obtained when 25 W are applied to CGO gives rise to a NFO/CGO ~ 1/6 (wt/wt) while this ratio changes to ~ 2/1 (wt/wt) when applying 8 W to the CGO target (XPS spectrum and SEM microstructure of this thin film in Supplementary information Figure S5). Figure 9 presents the total conductivity as a function of $pO_2$ (a) of different cerce thin films and (b) of reference CGO and NFO thin films. Data of the NFO/CGO 52/48 bulk material is also plotted for comparison in both graphs. Thin films annealed at 800°C. r.f. 25/25 W.
function of the $pO_2$ for two composites films deposited at 400 °C and annealed at 800 °C. The conduction character of the thin film is determined by the prevailing crystalline phase, in line with a simple additive behavior of conduction properties. Namely, the higher the amount of NFO phase, the higher the total conductivity (quite close to the values of the NFO film) and it is obtained the same $1/4$ slope characteristic of a predominant $p$-type electronic conductor. Accordingly, the higher the amount of CGO, the lower the total conductivity, with values similar to those of the CGO film but with a slight dependence on the $pO_2$. This dependence can be assigned to the electronic conductivity through the NFO electronic conducting pathways, and the smaller values at very low $pO_2$ can be attributed to three aspects: (i) $p$-type electronic character of sputtered NFO particles; (ii) the lower vol. fraction of ionic-phase; and also possibly (iii) limitations in the percolation among CGO grains (ionic pathways). Therefore, composite thin-film layers produced by applying a NFO/CGO r.f. power of 25/8 W resulted in the highest total conductivity for a NFO/CGO ratio of 2/1.

![Graph](image)

**Figure 8**: Total conductivity at 700°C as a function of the $pO_2$ of NFO/CGO composites films with different NFO/CGO ratios and reference NFO and CGO films, all deposited at 400 °C (a) and NFO/CGO ratios measured by XPS (b).

Conductivity relaxation profiles at 750 °C upon oxidation and reduction, i.e. step-change from air to pure oxygen and *vice versa*, are depicted in Figure 5 for NFO/CGO (1/6) and NFO thin films. Note that the relaxation curve of a CGO thin film in this range of $pO_2$
cannot be measured, as there is no change in conductivity in this range of $pO_2$. The relaxation process of the nanocomposite thin film is much faster than that of pure NFO thin film. As we are measuring thin films this can only be ascribed to faster surface exchange kinetics of the nanocomposite. By fitting the curves to equation 1, surface reaction, $k$ coefficients of $2.3 \times 10^{-7}$ and $8.7 \times 10^{-8}$ cm/s were obtained for oxidation and reduction of the nanocomposite film whereas $k$ values $1.8 \times 10^{-8}$ and $1.5 \times 10^{-8}$ cm/s were measured for oxidation and reduction of the NFO film.\[25\] Surface exchange is boosted by one order of magnitude faster by providing oxygen-ion conduction to the NFO film, i.e, by creating a highly-packed nanocomposite with CGO ionic phase. This phenomena has been previously observed for bulk NFO/CGO composites as inferred from pulse $O^{16}/O^{18}$ isotopic exchange measurements. The $k$ values of the composite thin film are in the same order of magnitude as those reported for $Ce_{0.69}Gd_{0.31}O_{2-\delta}$ single crystals ($k = 4 \times 10^{-8}$ cm/s at 750 °C) while a huge increase of this kinetic parameter is expected if electronic conductivity is promoted in the doped-ceria matrix.\[8b, 31\]

Figure 9: Conductivity relaxation curves at 750 °C of a NFO/CGO composite thin film (a) and a NFO thin film (b)

Aiming to check NFO/CGO nanocomposite thin film suitability for oxyfuel applications, the stability of both phases in the sample deposited at 400°C with an annealing at 800°C
was checked at 750°C for 48h in an atmosphere containing 250 ppm of SO₂, 5% of O₂, 3% H₂O and balanced with CO₂. XRD analysis are performed before and after treatment to confirm the absence of changes in the phase caused by SO₂, H₂O or CO₂. Figure 10 shows XRD patterns of the sample before and after the stabilization treatment where there are no changes in the phase before the treatment. Thus, the composite thin film appears to be stable under highly-demanding oxyfuel conditions where SO₂, H₂O or CO₂ are present.

![XRD patterns of NFO/CGO composite film deposited at 400°C after annealing at 800°C before and after stability treatment at 750°C for 48h in an atmosphere containing 250 ppm of SO₂, 5% of O₂, 3% H₂O and balanced with CO₂. NFO and CGO reference patterns are also showed.](image)

**Figure 10:** XRD patterns of NFO/CGO composite film deposited at 400°C after annealing at 800°C before and after stability treatment at 750°C for 48h in an atmosphere containing 250 ppm of SO₂, 5% of O₂, 3% H₂O and balanced with CO₂. NFO and CGO reference patterns are also showed.

Finally, the application of NFO/CGO thin film layers as oxygen transport membranes was studied by conducting O₂ permeation tests. A 150 nm-thick NFO/CGO layer was deposited on top of a BSCF asymmetric membrane (20 µm-thick dense layer on a porous support, see cross-section Figure 12a). Nanocomposite layers were deposited by applying an r.f. power of 25/8 W on the NFO/CGO target at 400 °C. NFO/CGO deposition on BSCF was selected to combine both high permeation features of BSCF membranes [16] and good stability of NFO/CGO under oxyfuel environments [9d, 10, 32]. Accordingly, the oxygen permeation was studied at different temperatures (1000 - 900 °C) and varying the CO₂ content in the sweep stream.
O₂ fluxes \( J(O₂) \) through the non-coated BSCF membrane suffer an important decay (Figure 11) when increasing CO₂ concentration in the sweep that becomes more significant at lower temperatures. Under pure CO₂ sweeping, the uncoated BSCF membrane exhibits \( J(O₂) \) of 0.66, 0.29 and 0.12 ml·min\(^{-1}\)·cm\(^{-2}\) at 1000, 950 and 900 °C, respectively, whereas under pure Ar sweeping O₂ fluxes are in the range of 10-7.4 ml·min\(^{-1}\)·cm\(^{-2}\). When the NFO/CGO layer is deposited on the BSCF membrane surface, the resulting membrane assembly still delivers high \( J(O₂) \) under clean conditions, thus proving both the proper ambipolar conduction and high surface exchange activity of the nanocomposite sputtered layer. Furthermore, the permeation decay of the membrane subjected to CO₂ environments is significantly lower than for the non-coated membrane. (Figure 11, note the log scale in y-axis) Under full CO₂ sweeping conditions, \( J(O₂) \) values of 3.8, 1.3 and 0.4 ml·min\(^{-1}\)·cm\(^{-2}\) at 1000, 950 and 900 °C are obtained, respectively. In a similar study performed on a screen-printed 10 µm-thick \( \text{NiFe}_2\text{O}_3\text{-Ce}_{0.8}\text{Tb}_{0.2}\text{O}_2\text{-δ} \) (NFO/CTO) membrane on a porous \( \text{La}_{0.6}\text{Sr}_{0.4}\text{Co}_{0.2}\text{Fe}_{0.8}\text{O}_{3-δ} \) support, \([15]\) the \( J(O₂) \) at 1000 °C through the membrane improved with regard to Ar sweeping. Better sweeping properties are observed for CO₂ at very high temperatures while the CO₂ higher thermal emissivity enables to increase temperature on membrane surface and subsequently the O₂ fluxes. \([9d, 33]\) Contrarily, the permeation of the NFO/CGO sputtered layer decreases when exposed to such environments at 1000-900 °C. The latter was previously observed by Luo et al., \([7, 10]\) and can be ascribed to O₂/CO₂ competitive adsorption processes inhibiting oxygen reactions on the surface active sites. \([7, 9d, 10, 33]\) Besides, a slight degradation can be identified in the nano-grained NFO/CGO layer after testing and thermal cycling (1040 °C to 700°C) (Figure S6) and this may contribute to this loss in performance. Initially, and as can be seen in Figure 12b, a dense 150 µm-thick NFO/CGO layer is deposited uniformly on top of BSCF surface, covering completely BSCF membrane surface (Figures 12c and d). After the thermal cycling resulting from characterization (Figure S7), the NFO/CGO layer partially detached or disappeared in some particular areas. Therefore, the interaction of BSCF membrane in direct contact with CO₂ subsequently produced a loss in permeation, indicating that the robustness of the 150 nm-thick layer is not sufficient for operation at 1000 °C. Further work for the optimization of the layer needs to be done in terms of thickness and uniformity while the optimal operation regime should be identified, typically below 900 °C.
According to the obtained permeation results, a good performance is observed for NFO/CGO nanocomposite layers when working as OTM under oxyfuel conditions, delivering high oxygen permeation values even when exposed to full CO$_2$ environments. Additionally, the use of NFO/CGO nanocomposite layers obtained by r.f. magnetron co-sputtering could be also considered for the protection of highly permeating materials like BSCF in applications where stability in harsh gas environments is indispensable.

**Figure 11**: Permeation results of the bare and co-sputtered membrane as a function of testing temperature and CO$_2$ concentration in the sweep gas. (Experimental conditions: 300 ml·min$^{-1}$ air feeding, 300 ml·min$^{-1}$ Ar/CO$_2$ mixtures sweeping)
4. Summary and conclusions

NiFe$_2$O$_4$ - Ce$_{0.8}$Gd$_{0.2}$O$_{2.5}$ (NFO – CGO) nanocomposite thin films were prepared by r.f. magnetron co-sputtering of individual NFO and CGO ceramic targets and optimized as a function of deposition temperature. The best microstructure and conduction properties were obtained for the film deposited at 400 ºC. The total transport properties, studied by total conductivity measurements as a function of the temperature and the $p$O$_2$, showed mixed electronic-ionic conduction due to the presence of the two highly-packed nano-grained phases, i.e., NFO electronic conducting phase and the CGO ionic phase. The p-type electronic behavior was correlated with the hole hopping between Ni$^{3+}$ - Ni$^{2+}$ (oxidation states of Ni measured by XPS) previously showed in the NFO thin films. The ratio of both phases was changed by applying different power to the ceramic targets and the expected amount of each deposited phase was measured by XPS. Furthermore, by changing ratio
between NFO and CGO in the deposition process, the thin films exhibited preferential ionic or electronic conductivity. Finally, the use of NFO/CGO thin films as oxygen transport membranes was studied by coating an asymmetric BSCF membrane. The resulting membrane assembly showed a remarkably better oxygen permeation performance in operation under CO₂-rich gas environments. Specifically, an improvement up to 3-5-fold rise in the fluxes was achieved under pure CO₂ atmosphere, with a peak flux of 3.8 ml·min⁻¹·cm⁻² at 1000 ºC.

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